XP132A1275SR



ETR1108_001a

Power MOSFET

■GENERAL DESCRIPTION

The XP132A1275SR is a P-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

The small SOP-8 package makes high density mounting possible.

■APPLICATIONS

- Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

■FEATURES

Low On-State Resistance: Rds(on)= 0.075Ω (Vgs=-4.5V)

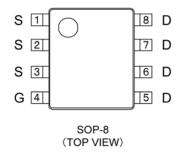
: Rds(on)=0.115 Ω (Vgs=-2.5V)

Ultra High-Speed Switching Driving Voltage : -2.5V **P-Channel Power MOSFET**

DMOS Structure

: SOP-8 **Package**

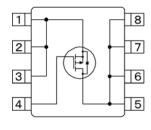
■PIN CONFIGURATION



■ PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTION
1~3	S	Source
4	G	Gate
5~8	D	Drain

■EQUIVALENT CIRCUIT



P-channel MOSFET (1 device built-in)

■ ABSOLUTE MAXIMUM RATINGS

Ia = 2						
PARAMETER	SYMBOL	RATINGS	UNITS			
Drain-Source Voltage	Vdss	-20	V			
Gate-Source Voltage	Vgss	±12	V			
Drain Current (DC)	ld	-5	Α			
Drain Current (Pulse)	ldp	-20	Α			
Reverse Drain Current	ldr	-5	Α			
Channel Power Dissipation *	Pd	2.5	W			
Channel Temperature	Tch	150	သိ			
Storage Temperature Range	Tstg	-55~150	သိ			

^{*} When implemented on a glass epoxy PCB

■ELECTRICAL CHARACTERISTICS

DC Characteristics

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds=-20V, Vgs=0V	-	-	-10	μΑ
Gate-Source Leak Current	lgss	Vgs=±12V, Vds=0V	-	-	±1	μΑ
Gate-Source Cut-Off Voltage	Vgs(off)	ld=-1mA, Vds=-10V	-0.5	-	-1.2	V
Drain-Source On-State Resistance *	Rds(on)	Id=-3A, Vgs=-4.5V	-	0.06	0.075	Ω
Drain-Source On-State Resistance		Id=-3A, Vgs=-2.5V	-	0.092	0.115	Ω
Forward Transfer Admittance *	Yfs	Id=-3A, Vds=-10V	-	8	-	S
Body Drain Diode Forward Voltage	Vf	If=-5A, Vgs=0V	-	-0.85	-1.1	V

^{*} Effective during pulse test.

Dynamic Characteristics

Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds=-10V, Vgs=0V f=1MHz	-	770	-	pF
Output Capacitance	Coss		-	440	-	pF
Feedback Capacitance	Crss		-	180	-	pF

Switching Characteristics

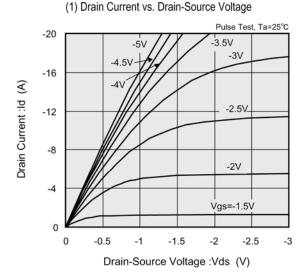
Ta = 25°C

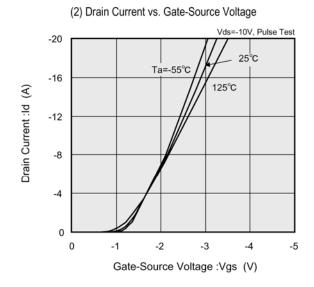
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	td (on)	Vgs=-5V, Id=-3A Vdd=-10V	ı	10	ı	ns
Rise Time	tr		-	25	-	ns
Turn-Off Delay Time	td (off)		-	45	-	ns
Fall Time	tf		-	40	-	ns

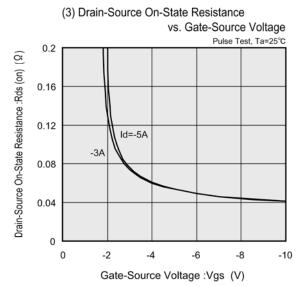
Thermal Characteristics

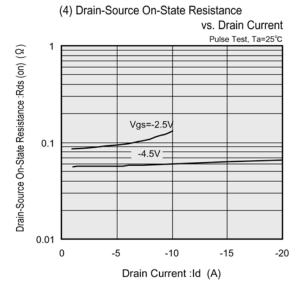
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	Rth (ch-a)	Implement on a glass epoxy resin PCB	-	50	-	°C/W

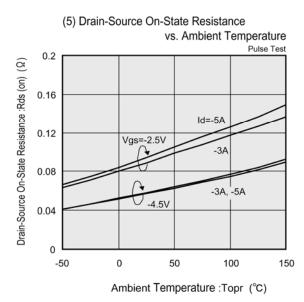
■TYPICAL PERFORMANCE CHARACTERISTICS

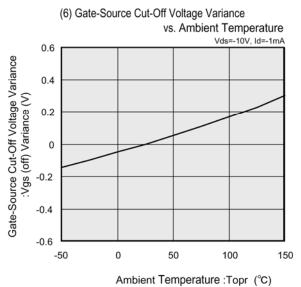




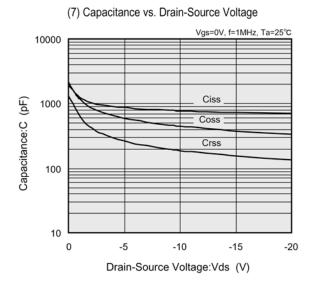


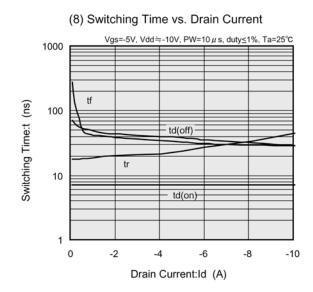


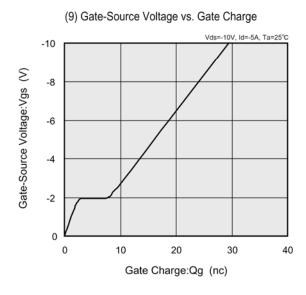


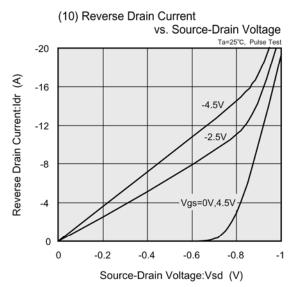


■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

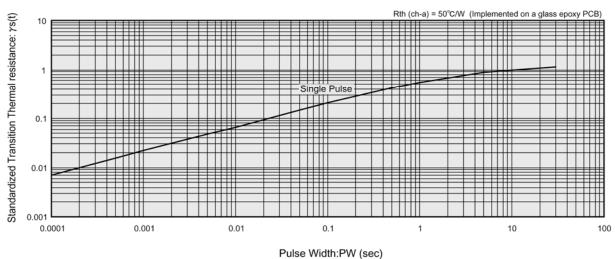












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